

September 1998

54FCT244

Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The 'FCT244 is an octal buffer and line driver with TRI-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

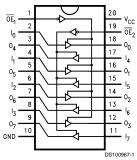
- Non-inverting buffers
- Output sink capability of 48 mA, source capability of 12 mA
- TRI-STATE outputs drive lines or buffer memory address registers
- TTL input and output level compatible
- CMOS power consumption
- Standard Microcircuit Drawing (SMD) 5962-8763001

Ordering Code

Military	Package Description	
	Number	
54FCT244DMQB	J20A	20-Lead Ceramic Dual-In-Line
54FCT244FMQB	W20A	20-Lead Cerpack
54FCT244LMQB	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Connection Diagrams

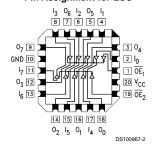
Pin Assignment for DIP and Flatpak



Pin	Description			
Names				
\overline{OE}_1 , \overline{OE}_2	Output Enable Input			
	(Active Low)			
I ₀ -I ₇	Inputs			
O ₀ -O ₇	Outputs			

OE ₁	I ₀₋₃	O ₀₋₃	OE ₂	I ₄₋₇	0 ₄₋₇
Н	Х	Z	Н	Х	Z
L	Н	Н	L	Н	Н
L	L	L	L	L	L

Pin Assignment for LCC



H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

 $\begin{array}{ll} \mbox{Storage Temperature} & -65\mbox{°C to } +150\mbox{°C} \\ \mbox{Ambient Temperature under Bias} & -55\mbox{°C to } +125\mbox{°C} \\ \end{array}$

Junction Temperature under Bias

 $\begin{array}{ll} \text{Ceramic} & -55^{\circ}\text{C to } +175^{\circ}\text{C} \\ \text{V}_{\text{CC}} \text{ Pin Potential to Ground Pin} & -0.5V \text{ to } +7.0V \end{array}$

Input Voltage (Note 2) -0.5V to +7.0V

Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Any Output

in the Disabled or

Power-Off State $\begin{array}{cc} -0.5 \text{V to } 5.5 \text{V} \\ \text{in the HIGH State} \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA) DC Latchup Source Current -500 mA

Recommended Operating Conditions

Free Air Ambient Temperature

Military –55°C to +125°C

Supply Voltage

DC Electrical Characteristics for 'FCT Family Devices

Symbol	Parameter		FCT244		Units	V _{cc}	Conditions
			Min	Max	1		
V _{IH}	Input HIGH Voltage		2.0		V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	54FCT	4.3		V	Min	I _{OH} = -300 μA
		54FCT	2.4				I _{OH} = -12 mA
V _{OL}	Output LOW Voltage	54FCT		0.2	V	Min	I _{OL} = 300 μA
		54FCT		0.55			I _{OL} = 48 mA
I _{IH}	Input HIGH Current			5	μΑ	Max	V _{IN} = V _{CC}
I _{IL}	Input LOW Current			-5	μΑ	Max	V _{IN} = 0.0V
I _{OZ}	Maximum TRI-STATE Current F LOW	IIGH or		±10	μA	Max	$V_{IN} = 0.0V$ or $V_{IN} = V_{CC}$
I _{os}	Output Short-Circuit Current			-60	mA	Max	V _{OUT} = 0.0V
I _{CCQ}	Quiescent Power Supply Curren	t		1.5	mA	Max	V_{IN} < 0.2V or V_{IN} 5.3V, V_{CC} = 5.5V
Δl _{CC}	Quiescent Power Supply Current			2.0	mA	Max	$V_{I} = 3.4V, V_{CC} = 5.5V$
I _{CCD}	Dynamic I _{cc}			0.4	mA/ MHz	Max	Outputs Open, V_{CC} = 5.5V, V_{IN} 5.3V or V_{IN} < 0.2V, One Bit Toggling, 50% Duty Cycle, \overline{OE} = GND, LE = V_{CC}
Гсст	Total Power Supply Current			6.0	mA	Max	Outputs Open, f_{CP} = 10 MHz, V_{CC} = 5.5V, V_{IN} 5.3V or V_{IN} < 0.2V, One Bit Toggling, 50% Duty Cycle, \overline{OE} = GND, LE = V_{CC}

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

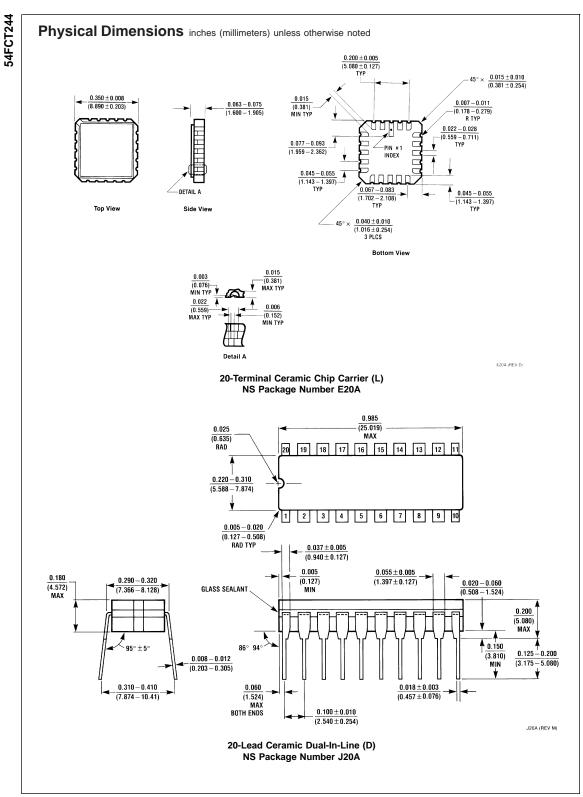
Symbol	Parameter	54	FCT	Units	Fig.
		T _A = -55°C to +125°C			No.
		$V_{CC} = 4$.5V-5.5V		
		C _L = 50 pF			
		Min	Max		
t _{PLH}	Propagation Delay	1.5	7.5	ns	
t_{PHL}	Data to Outputs	1.5	7.5		
t _{PZH}	Output Enable	1.5	10.5	ns	
t_{PZL}	Time	1.5	10.5		
t _{PHZ}	Output Disable	1.5	8.0	ns	
t_{PLZ}	Time	1.5	8.0		

Capacitance

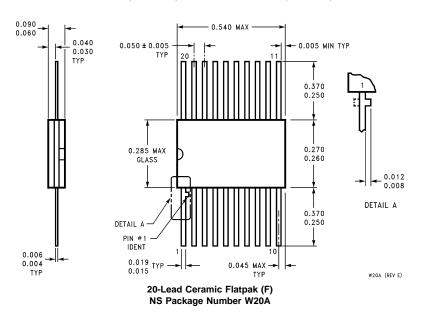
Symbol	Parameter	Max	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	10.0	pF	V _{CC} = 0V
C _{OUT} (Note 5)	Output Capacitance	12.0	pF	V _{CC} = 5.0V

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

3 www.national.com



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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